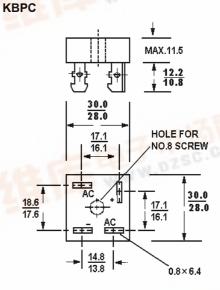
## HIGH CURRENT SINGLE-PHASE SILICON BRIDGE RECTIFIERS

**REVERSE VOLTAGE: 50V to 1000V** 

**FORWARD CURRENT: 25A** 

#### **Features**

- Surge overload 300 Amperes peak
- Low power loss, high efficiency
- Low reverse leakage current



Dimensions in mm

## **Absolute Maximum Ratings and Characteristics**

Rating at 25°C ambient temperature unless otherwise specified. resistive or inductive load 60 Hz,. For capacitive load current by 20%.

Characteristic Characteristic	KBPC	KBPC	KBPC	KBPC	KBPC	KBPC	KBPC	Units
	25005	2501	2502	2504	2506	2508	2510	
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	٧
Maximum Average Forward Rectified  Current at T <sub>C</sub> = 55 °C	25							А
Peak Forward Surge Current, 8.3ms single half Sine-wave superimposed on rated load	300							А
Maximum Forward Voltage at 12.5A DC and 25°C	1.2							V
Maximum Reverse Current at $T_A = 25^{\circ}$ C at Rated DC Blocking Voltage $T_A = 125^{\circ}$ C	10 1000							uA
Typical Junction Capacitance (Note 1)	300							pF
Typical Thermal Resistance (Note 2)	1.9							°C/W
Operating Temperature Range T <sub>J</sub>	-55 to +125							°C
Storage Temperature Range T <sub>S</sub>	-55 to +150							°C

Notes: 1. Measured at 1 MHz and applied reverse voltage of 4.0VDC.

2. Thermal resistance from junction t case per leg.



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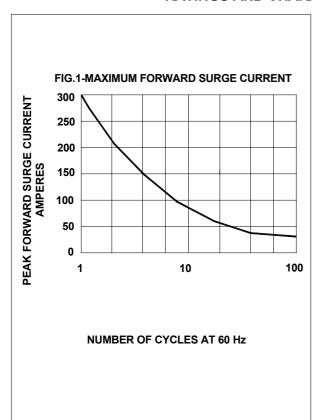


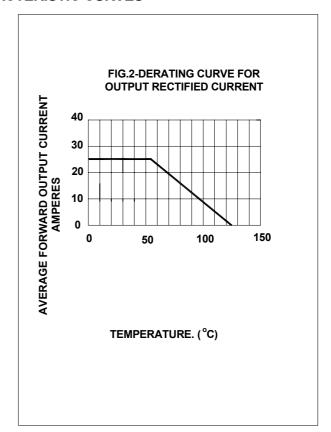


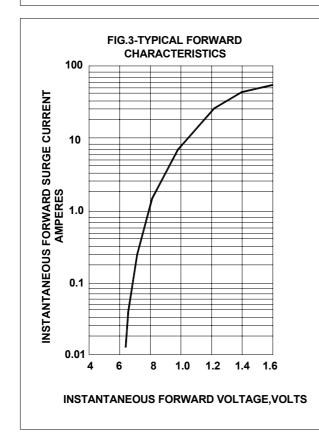


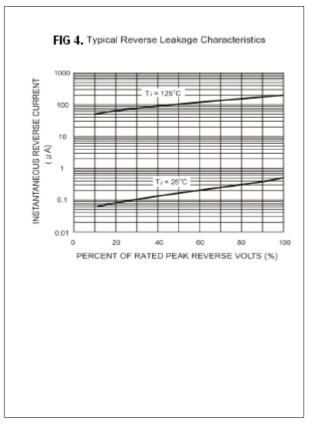
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### **RATINGS AND CHARACTERISTIC CURVES**















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